

50 mA, High Voltage, Micropower Linear Regulator

ADP1720

FEATURES

Wide input voltage range: 4 V to 28 V Maximum output current: 50 mA Low light load current:

28 μA at 0 μA load 35 μA at 100 μA load Low shutdown current: 0.7 μA

Low dropout voltage: 275 mV @ 50 mA load

Initial accuracy: ±0.5%

Accuracy over line, load, and temperature: $\pm 2\%$ Stable with small 1µF ceramic output capacitor Fixed 3.3 V and 5.0 V output voltage options Adjustable output voltage option: 1.225 V to 5.0 V Current limit and thermal overload protection Logic controlled enable

Space-saving thermally enhanced MSOP package

APPLICATIONS

DC-to-DC post regulation PCMCIA regulation Keep-alive power in portable equipment Industrial applications

GENERAL DESCRIPTION

The ADP1720 is a high voltage, micropower, low dropout linear regulator. Operating over a very wide input voltage range of 4 V to 28 V, the ADP1720 can provide up to 50 mA of output current. With just 28 μA of quiescent supply current and a micropower shutdown mode, this device is ideal for applications that require low quiescent current.

The ADP1720 is available in fixed output voltages of 3.3 V and 5.0 V. An adjustable version is also available, which allows the output to be set anywhere between 1.225 V and 5.0 V. An enable function that allows external circuits to turn on and turn off the ADP1720 output is available. For automatic startup, the enable (EN) pin can be connected directly to the input rail.

TYPICAL APPLICATION CIRCUITS

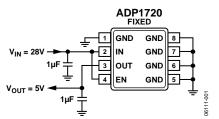


Figure 1. ADP1720 with Fixed Output Voltage, 5.0 V

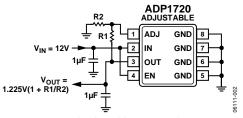


Figure 2. ADP1720 with Adjustable Output Voltage, 1.225 V to 5.0 V

The ADP1720 is optimized for stable operation with small 1 μ F ceramic output capacitors, allowing for good transient performance while occupying minimal board space.

The ADP1720 operates from -40°C to +125°C and uses current limit protection and thermal overload protection circuits to prevent damage to the device in adverse conditions.

Available in a small thermally enhanced MSOP package, the ADP1720 provides a compact solution with low thermal resistance.

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REVISION HISTORY

7/07—Rev. 0 to Rev. A	
Change to Figure 1	1
Changes to Table 1	3
Changes to Ordering Guide	15
2/07—Revision 0: Initial Version	

SPECIFICATIONS

 $V_{\rm IN}$ = 12 V, $I_{\rm OUT}$ = 100 μA , $C_{\rm IN}$ = $C_{\rm OUT}$ = 1 μF , $T_{\rm A}$ = 25°C, unless otherwise noted.

Table 1.

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
INPUT VOLTAGE RANGE	V _{IN}	$T_J = -40^{\circ}\text{C to } +125^{\circ}\text{C}$	4		28	V
OPERATING SUPPLY CURRENT	I _{GND}	$\begin{aligned} I_{OUT} &= 0 \ \mu A \\ I_{OUT} &= 0 \ \mu A, V_{IN} = V_{OUT} + 0.5 \ V \ or \ 4 \ V \ (whichever is greater), T_J &= -40 ^{\circ} C \ to \ +125 ^{\circ} C \end{aligned}$		28	80	μA μA
		Ιουτ = 100 μΑ		35		μΑ
		I_{OUT} = 100 μ A, V_{IN} = V_{OUT} + 0.5 V or 4 V (whichever is greater), T_J = -40°C to +125°C			120	μΑ
		I _{OUT} = 1 mA		74		μΑ
		$I_{OUT} = 1$ mA, $V_{IN} = V_{OUT} + 0.5$ V or 4 V (whichever is greater), $T_J = -40^{\circ}$ C to $+125^{\circ}$ C			340	μΑ
		I _{OUT} = 10 mA		300		μΑ
		$I_{OUT} = 10$ mA, $V_{IN} = V_{OUT} + 0.5$ V or 4 V (whichever is greater), $T_J = -40^{\circ}$ C to $+125^{\circ}$ C			900	μΑ
		100 μA $<$ I _{OUT} $<$ 50 mA, V _{IN} $=$ V _{OUT} $+$ 0.5 V or 4 V (whichever is greater), T _J $=$ -40° C to $+125^{\circ}$ C		1185	2115	μΑ
SHUTDOWN CURRENT	I _{GND-SD}	EN = GND		0.7		μΑ
		$EN = GND, T_J = -40^{\circ}C \text{ to } +125^{\circ}C$			1.5	μΑ
OUTPUT						
Fixed Output	V _{OUT}	Ιουτ = 100 μΑ	-0.5		+0.5	%
Voltage Accuracy		100 μA < I _{OUT} < 50 mA	-1		+1	%
A 12		$100 \mu\text{A} < \text{I}_{\text{OUT}} < 50 \text{mA}, T_{\text{J}} = -40^{\circ}\text{C to} + 125^{\circ}\text{C}$	-2	4 2252	+2	%
Adjustable Output ¹	V _{OUT}	Ιουτ = 100 μΑ	1.2188	1.2250	1.2311	V
Voltage Accuracy		100 μ A < I_{OUT} < 50 mA 100 μ A < I_{OUT} < 50 mA, T_J = -40°C to +125°C	1.2127 1.2005		1.2372 1.2495	V
Noise (10 Hz to 100 kHz)	OUT _{NOISE}	V _{OUT} = 1.6 V, C _{OUT} = 1 μF	1.2003	146	1.2793	μV rms
14013C (10112 to 100 KHZ)	OOTNOISE	V _{OUT} = 1.6 V, C _{OUT} = 10 μF		124		μV rms
		$V_{OUT} = 5 \text{ V, } C_{OUT} = 1 \mu\text{F}$		340		μV rms
		$V_{OUT} = 5 \text{ V, } C_{OUT} = 10 \mu\text{F}$		266		μV rms
REGULATION		1001 0 17 0001 10 p.				μνιιισ
Line Regulation	$\Delta V_{OUT}/\Delta V_{IN}$	$V_{IN} = (V_{OUT} + 0.5 \text{ V}) \text{ to } 28 \text{ V}, T_J = -40^{\circ}\text{C to } +125^{\circ}\text{C}$	-0.02		+0.02	%/V
Load Regulation ²	ΔVουτ/ΔΙουτ	1 mA < louπ < 50 mA	0.02	0.001	. 0.02	%/mA
oaaga.ao	2 7 00 17 2 100 1	$1 \text{ mA} < I{OUT} < 50 \text{ mA}, T_J = -40^{\circ}\text{C to} + 125^{\circ}\text{C}$			0.005	%/mA
DROPOUT VOLTAGE ³	V _{DROPOUT}	louт = 10 mA		55		mV
	1 51101 001	$I_{OUT} = 10 \text{ mA}, T_J = -40^{\circ}\text{C to } +125^{\circ}\text{C}$			105	mV
		I _{OUT} = 50 mA		275		mV
		$I_{OUT} = 50 \text{ mA}, T_J = -40^{\circ}\text{C to } +125^{\circ}\text{C}$			480	mV
START-UP TIME ⁴	T _{START-UP}			200		μs
CURRENT LIMIT THRESHOLD ⁵	I _{LIMIT}		55	90	140	mA
THERMAL CHARACTERISTICS						
Thermal Shutdown Threshold	TS _{SD}	T _J rising		150		°C
Thermal Shutdown Hysteresis	TS _{SD-HYS}			15		°C
EN CHARACTERISTICS						
EN Input						
Logic High	V _{IH}	$4 \text{ V} \leq \text{V}_{\text{IN}} \leq 28 \text{ V}$	1.8			V
Logic Low	V _{IL}	$4 \text{ V} \leq \text{V}_{\text{IN}} \leq 28 \text{ V}$			0.4	V
Leakage Current	V _{I-LEAKAGE}	EN = GND EN = IN		0.1 0.5	1 1	μΑ μΑ
ADJ INPUT BIAS CURRENT (ADP1720 ADJUSTABLE)	ADJ _{I-BIAS}			30	100	nA

Parameter	Symbol	Conditions	Min Typ	Max	Unit
POWER SUPPLY REJECTION RATIO	PSRR	$f = 120 \text{ Hz}, V_{IN} = 8 \text{ V}, V_{OUT} = 1.6 \text{ V}$	-90		dB
		$f = 1 \text{ kHz}, V_{IN} = 8 \text{ V}, V_{OUT} = 1.6 \text{ V}$	-80		dB
		$f = 10 \text{ kHz}, V_{IN} = 8 \text{ V}, V_{OUT} = 1.6 \text{ V}$	-60		dB
		$f = 120 \text{ Hz}, V_{IN} = 8 \text{ V}, V_{OUT} = 5 \text{ V}$	-83		dB
		$f = 1 \text{ kHz}, V_{IN} = 8 \text{ V}, V_{OUT} = 5 \text{ V}$	-70		dB
		$f = 10 \text{ kHz}, V_{IN} = 8 \text{ V}, V_{OUT} = 5 \text{ V}$	-50		dB

¹ Accuracy when OUT is connected directly to ADJ. When OUT voltage is set by external feedback resistors, absolute accuracy in adjust mode depends on the tolerances of resistors used.

² Based on an end-point calculation using 1 mA and 50 mA loads. See Figure 6 for typical load regulation performance for loads less than 1 mA.

³ Dropout voltage is defined as the input to output voltage differential when the input voltage is set to the nominal output voltage. This applies only for output voltages above 4 V.

⁴ Start-up time is defined as the time between the rising edge of EN to OUT being at 95% of its nominal value. ⁵ Current limit threshold is defined as the current at which the output voltage drops to 90% of the specified typical value. For example, the current limit for a 5.0 V output voltage is defined as the current that causes the output voltage to drop to 90% of 5.0 V, or 4.5 V.

ABSOLUTE MAXIMUM RATINGS

Table 2.

Rating
-0.3 V to +30 V
-0.3 V to IN or +6 V (whichever is less)
-0.3 V to +30 V
−0.3 V to +6 V
−65°C to +150°C
-40°C to +125°C
JEDEC J-STD-020

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

THERMAL RESISTANCE

 θ_{JA} is specified for the worst-case conditions, that is, a device soldered in a circuit board for surface-mount packages.

Table 3. Thermal Resistance

Package Type	θја	θις	Unit
8-Lead MSOP	118	57	°C/W

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS



Figure 3. 8-Lead MSOP



Figure 4. 8-Lead MSOP

Table 4. Pin Function Descriptions

ADP1720 Fixed	ADP1720 Adjustable		
Pin No.	Pin No.	Mnemonic	Description
1	N/A	GND	This pin is internally connected to ground.
N/A	1	ADJ	Adjust. A resistor divider from OUT to ADJ sets the output voltage.
2	2	IN	Regulator Input Supply. Bypass IN to GND with a 1 µF or greater capacitor.
3	3	OUT	Regulated Output Voltage. Bypass OUT to GND with a 1 µF or greater capacitor.
4	4	EN	Enable Input. Drive EN high to turn on the regulator; drive it low to turn off the regulator. For automatic startup, connect EN to IN.
5	5	GND	Ground.
6	6	GND	Ground.
7	7	GND	Ground.
8	8	GND	Ground.

TYPICAL PERFORMANCE CHARACTERISTICS

 $V_{\rm IN}$ = 12 V, $V_{\rm OUT}$ = 5 V, $I_{\rm OUT}$ = 100 μ A, $C_{\rm IN}$ = $C_{\rm OUT}$ = 1 μ F, $T_{\rm A}$ = 25°C, unless otherwise noted.

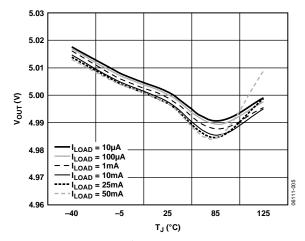


Figure 5. Output Voltage vs. Junction Temperature

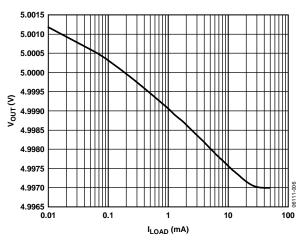


Figure 6. Output Voltage vs. Load Current

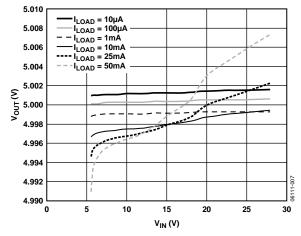


Figure 7. Output Voltage vs. Input Voltage

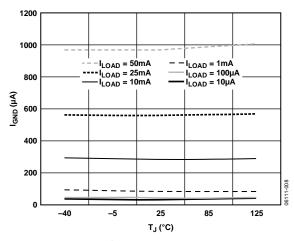


Figure 8. Ground Current vs. Junction Temperature

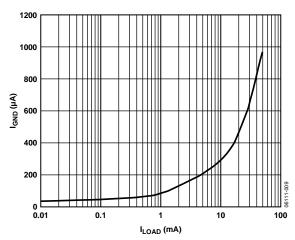


Figure 9. Ground Current vs. Load Current

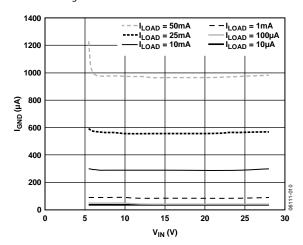


Figure 10. Ground Current vs. Input Voltage

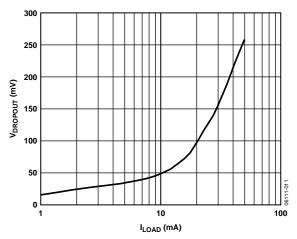


Figure 11. Dropout Voltage vs. Load Current

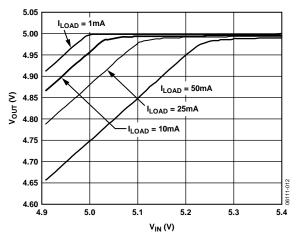


Figure 12. Output Voltage vs. Input Voltage (in Dropout)

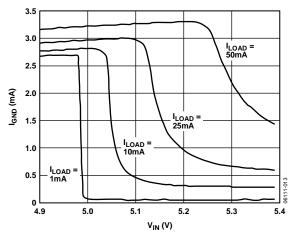


Figure 13. Ground Current vs. Input Voltage (in Dropout)

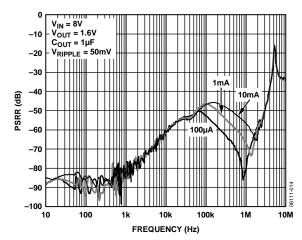


Figure 14. Power Supply Rejection Ratio vs. Frequency (1.6 V Adjustable Output)

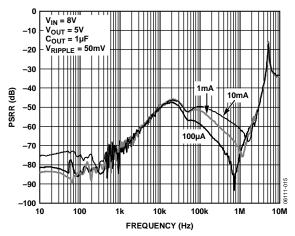


Figure 15. Power Supply Rejection Ratio vs. Frequency (5.0 V Fixed Output)

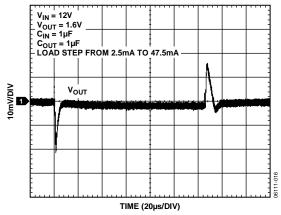


Figure 16. Load Transient Response

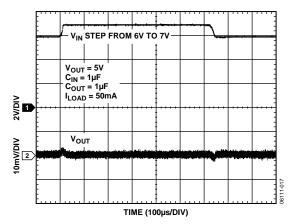


Figure 17. Line Transient Response

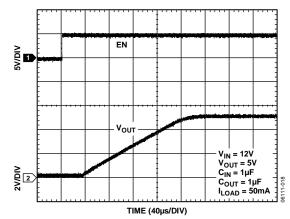


Figure 18. Start-Up Time

THEORY OF OPERATION

The ADP1720 is a low dropout, BiCDMOS linear regulator that operates from a 4 V to 28 V input rail and provides up to 50 mA of output current. Ground current in shutdown mode is typically 700 nA. The ADP1720 is stable and provides high power supply rejection ratio (PSRR) and excellent line and load transient response with just a small 1 μ F ceramic output capacitor.

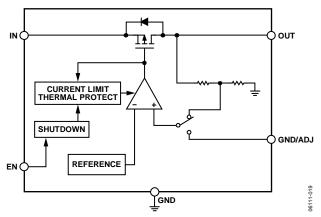


Figure 19. Internal Block Diagram

Internally, the ADP1720 consists of a reference, an error amplifier, a feedback voltage divider, and a DMOS pass transistor. Output current is delivered via the DMOS pass device, which is controlled by the error amplifier. The error amplifier compares the reference voltage with the feedback voltage from the output and amplifies the difference. If the feedback voltage is lower than the reference voltage, the gate of the DMOS device is pulled lower, allowing more current to pass and increasing the output voltage. If the feedback voltage is higher than the reference voltage, the gate of the PNP device is pulled higher, allowing less current to pass and decreasing the output voltage.

The ADP1720 is available in two versions, one with fixed output voltage options (see Figure 1) and one with an adjustable output voltage (see Figure 2). The fixed output voltage options are set internally to either 5.0 V or 3.3 V, using an internal feedback network. The adjustable output voltage can be set to between 1.225 V and 5.0 V by an external voltage divider connected from OUT to ADJ. The ADP1720 uses the EN pin to enable and disable the OUT pin under normal operating conditions. When EN is high, OUT turns on; when EN is low, OUT turns off. For automatic startup, EN can be tied to IN.

ADJUSTABLE OUTPUT VOLTAGE (ADP1720 ADJUSTABLE)

The ADP1720 adjustable version can have its output voltage set over a 1.225 V to 5.0 V range. The output voltage is set by connecting a resistive voltage divider from OUT to ADJ. The output voltage is calculated using the equation

$$V_{OUT} = 1.225 \text{ V} (1 + R1/R2)$$
 (1)

where:

R1 is the resistor from OUT to ADJ. *R2* is the resistor from ADJ to GND.

To make calculation of R1 and R2 easier, Equation 1 can be rearranged as follows:

$$R1 = R2 \left[(V_{OUT}/1.225) - 1 \right] \tag{2}$$

The maximum bias current into ADJ is 100 nA; therefore, when less than 0.5% error is due to the bias current, use values less than 60 k Ω for R2.

APPLICATIONS INFORMATION CAPACITOR SELECTION

Output Capacitor

The ADP1720 is designed for operation with small, space-saving ceramic capacitors, but it functions with most commonly used capacitors as long as care is taken about the effective series resistance (ESR) value. The ESR of the output capacitor affects stability of the LDO control loop. A minimum of 1 μF capacitance with an ESR of 500 m Ω or less is recommended to ensure stability of the ADP1720. Transient response to changes in load current is also affected by output capacitance. Using a larger value of output capacitance improves the transient response of the ADP1720 to large changes in load current. Figure 20 and Figure 21 show the transient responses for output capacitance values of 1 μF and 10 μF , respectively.

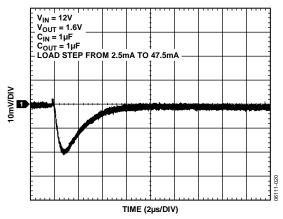


Figure 20. Output Transient Response, 1 μF

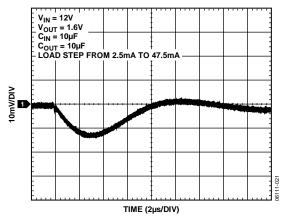


Figure 21. Output Transient Response, 10 μF

Input Bypass Capacitor

Connecting a 1 μF capacitor from IN to GND reduces the circuit sensitivity to printed circuit board (PCB) layout, especially when encountering long input traces or high source impedance. If greater than 1 μF of output capacitance is required, it is recommended that the input capacitor be increased to match it.

Input and Output Capacitor Properties

Any good quality ceramic capacitors can be used with the ADP1720, as long as they meet the minimum capacitance and maximum ESR requirements. Ceramic capacitors are manufactured with a variety of dielectrics, each with different behavior over temperature and applied voltage. Capacitors must have a dielectric adequate to ensure the minimum capacitance over the necessary temperature range and dc bias conditions. X5R or X7R dielectrics with a voltage rating of 6.3 V or 10 V are recommended for the output capacitor. X5R or X7R dielectrics with a voltage rating of 50 V or higher are recommended for the input capacitor.

Y5V and Z5U dielectrics are not recommended, due to their poor temperature and dc bias characteristics.

CURRENT LIMIT AND THERMAL OVERLOAD PROTECTION

Current limit and thermal overload protection circuits on the ADP1720 protect the part from damage caused by excessive power dissipation. The ADP1720 is designed to current limit when the output load reaches 90 mA (typical). When the output load exceeds 90 mA, the output voltage is reduced to maintain a constant current limit.

Thermal overload protection is included, which limits the junction temperature to a maximum of 150°C (typical). Under extreme conditions (that is, high ambient temperature and power dissipation), when the junction temperature starts to rise above 150°C, the output is turned off, reducing the output current to zero. When the junction temperature drops below 135°C, the output is turned on again, and output current is restored to its nominal value.

Consider the case where a hard short from OUT to GND occurs. At first, the ADP1720 current limits so that only 90 mA is conducted into the short. If self-heating of the junction is great enough to cause its temperature to rise above 150°C, thermal shutdown activates, turning off the output and reducing the output current to zero. As the junction temperature cools and drops below 135°C, the output turns on and conducts 90 mA into the short, again causing the junction temperature to rise above 150°C. This thermal oscillation between 135°C and 150°C causes a current oscillation between 90 mA and 0 mA, which continues as long as the short remains at the output.

Current and thermal limit protections are intended to protect the device against accidental overload conditions. For reliable operation, device power dissipation must be externally limited so that junction temperatures do not exceed 125°C.

THERMAL CONSIDERATIONS

To guarantee reliable operation, the junction temperature of the ADP1720 must not exceed 125°C. To ensure the junction temperature stays below this maximum value, the user needs to be aware of the parameters that contribute to junction temperature changes. These parameters include ambient temperature, power dissipation in the power device, and thermal resistances between the junction and ambient air (θ_{JA}). The θ_{JA} number is dependent on the package assembly compounds used and the amount of copper to which the GND pins of the package are soldered on the PCB. Table 5 shows typical θ_{JA} values of the 8-lead MSOP package for various PCB copper sizes.

Table 5.

Copper Size (mm²)	θ _{JA} (°C/W)
01	118
50	99
100	77
300	75
500	74

¹ Device soldered to minimum size pin traces.

The junction temperature of the ADP1720 can be calculated from the following equation:

$$T_I = T_A + (P_D \times \theta_{IA}) \tag{3}$$

where:

 T_A is the ambient temperature.

 P_D is the power dissipation in the die, given by

$$P_D = [(V_{IN} - V_{OUT}) \times I_{LOAD}] + (V_{IN} \times I_{GND})$$

$$\tag{4}$$

where:

 I_{LOAD} is the load current.

 I_{GND} is the ground current.

 V_{IN} and V_{OUT} are input and output voltages, respectively.

Power dissipation due to ground current is quite small and can be ignored. Therefore, the junction temperature equation simplifies to the following:

$$T_{J} = T_{A} + \{ [(V_{IN} - V_{OUT}) \times I_{LOAD}] \times \theta_{JA} \}$$
 (5)

As shown in Equation 5, for a given ambient temperature, input-to-output voltage differential, and continuous load current, there exists a minimum copper size requirement for the PCB to ensure that the junction temperature does not rise above 125°C. Figure 22 to Figure 27 show junction temperature calculations for different ambient temperatures, load currents, $V_{\rm IN}$ to $V_{\rm OUT}$ differentials, and areas of PCB copper.

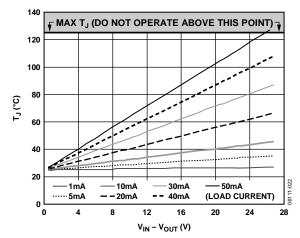


Figure 22. 300 mm² of PCB Copper, $T_A = 25$ °C

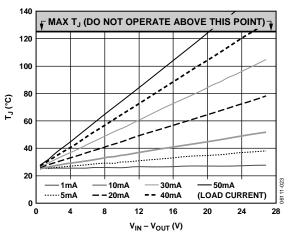


Figure 23. 100 mm² of PCB Copper, $T_A = 25$ °C

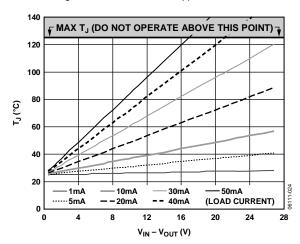


Figure 24. 0 mm² of PCB Copper, $T_A = 25$ °C

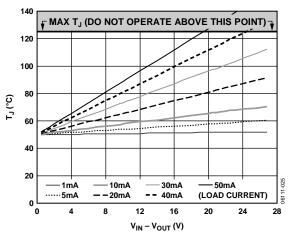


Figure 25. 300 mm² of PCB Copper, $T_A = 50$ °C

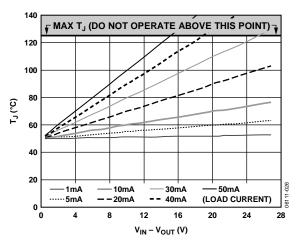


Figure 26. 100 mm² of PCB Copper, $T_A = 50$ °C

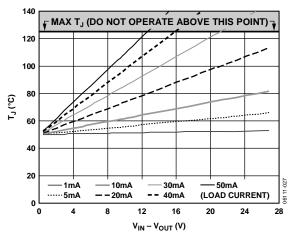


Figure 27. 0 mm² of PCB Copper, $T_A = 50$ °C

PRINTED CIRCUIT BOARD LAYOUT CONSIDERATIONS

Heat dissipation from the package can be improved by increasing the amount of copper attached to the pins of the ADP1720. However, as can be seen from Table 5, a point of diminishing returns eventually is reached, beyond which an increase in the copper size does not yield significant heat dissipation benefits.

Place the input capacitor as close as possible to the IN and GND pins. Place the output capacitor as close as possible to the OUT and GND pins. Use of 0402 or 0603 size capacitors and resistors achieves the smallest possible footprint solution on boards where area is limited.

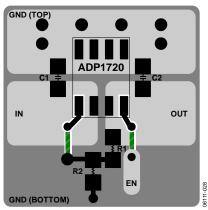
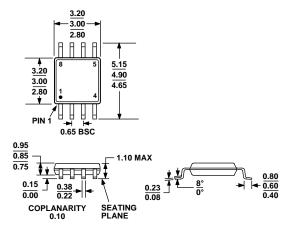


Figure 28. Example PCB Layout

OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MO-187-AA

Figure 29. 8-Lead Mini Small Outline Package [MSOP] (RM-8) Dimensions shown in millimeters

ORDERING GUIDE

		Output			
Model	Temperature Range	Voltage (V)	Package Description	Package Option	Branding
ADP1720ARMZ-5-R7 ¹	-40°C to +125°C	5	8-Lead MSOP	RM-8	L30
ADP1720ARMZ-3.3-R7 ¹	-40°C to +125°C	3.3	8-Lead MSOP	RM-8	L2Z
ADP1720ARMZ-R7 ¹	-40°C to +125°C	1.225 to 5	8-Lead MSOP	RM-8	L2M
ADP1720-5-EVALZ ¹		5	Evaluation Board		
ADP1720-3.3-EVALZ ¹		3.3	Evaluation Board		
ADP1720-EVALZ ¹		1.225 to 5	Evaluation Board		

 $^{^{1}}$ Z = RoHS Compliant Part.

ADP1720	
ADP1720	

NOTES

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